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Tuning Adhesion at Metal/Oxide Interfaces by Surface Hydroxylation

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Abstract

The control of adhesion at metal/oxide interfaces is of key importance in modern applications, whenever three-dimensional metal clusters or two-dimensional metal overlayers are to be synthesized on an oxide support. By focusing on the zinc/alumina system, we address here one of the long-standing issues in this context, which is the poor wetting of wide band-gap oxides by noble and post-transition metals. It has recently been recognized to have detrimental industrial consequences for the adhesion of anti-corrosive zinc coatings to new high strength steels grades. We have combined photoemission, thermal desorption and plasmonics with atomistic simulation to describe the energetics of zinc deposits on dry and hydroxylated α -Al₂O₃(0001) surfaces. Both experimental and computational results show that an activated reaction of the metal with the OH-covered surface, followed by hydrogen desorption, produces dispersed interfacial moieties involving both oxidized Zn species and undercoordinated oxygen ions, that lead to a significant improvement of adsorption/adhesion characteristics on the hydroxylated surface. In particular, the key role of interfacial undercoordinated anions, remnants of the hydroxylation layer, is highlighted for the first time,

pointing to a general mechanism by which surface hydroxylation appears as a promising route towards a systematic improvement of wide band gap oxide wetting by metals.

1 Introduction

Metal-oxide interfaces have been intensively studied because of their scientific and commercial importance. The many applications in which they are involved (e.g. microelectronics, thermal or optical coatings, catalysis) require quite diverse metal growth modes depending on the desired properties. For example, the need for three-dimensional nanoparticles of defined shape and size for catalysts contrasts with the development of two-dimensional growth for functional coatings. Therefore, beyond the understanding of the mechanisms at work during the build-up of metal-oxide interfaces,¹⁻⁶ there is a constant search for methods that can help to keep adhesion under control. One such means is surface hydroxylation. The often invoked ability of OH groups to increase the adhesion energy via a charge transfer with the metal adlayer^{5,7,8} is of extreme relevance since hydroxylation is an ubiquitous source of active sites at most oxide surfaces. The issue has been intensively studied on the α -Al₂O₃(0001) surface

1 which shows a propensity to be hydroxylated
2 by dissociative adsorption of water.^{9–12}

3 Interactions of Cu,^{13,14} Co,⁷ Ti and Al⁵ met-
4 als with hydroxylated alumina have been specif-
5 ically studied and a formation of a fraction of
6 oxidized metal monolayer upon interaction with
7 surface hydroxyls has been reported. However,
8 beyond the demonstrated strong interaction of
9 the oxidized species qualified as anchors with
10 the alumina substrate, little is known on its
11 consequences for the interface adhesion and ox-
12 ide wetting by the multilayer metal film. In-
13 deed, the key issue for the cohesive metal/oxide
14 cleavage is the capability of these strongly
15 bonded interfacial species to chemically bind
16 also with the subsequently deposited metal lay-
17 ers. As will be shown in our present study,
18 it is directly linked to the presence of under-
19 coordinated anions and to the degree of inter-
20 face dehydrogenation.

21 We have considered Zn deposits on α -
22 Al₂O₃(0001), which is a model system for the
23 galvanization process of advanced high strength
24 steels, subject to surface segregation of oxides
25 of electro-positive strengthening elements, such
26 as Al, Mn, or Si^{15–19} (see SI Section S1). More-
27 over, the Zn/alumina system has several ad-
28 vantages. Firstly, it displays a favorable large
29 difference in binding energies between non-
30 reactive and reactive metal adsorption,^{8,20,21}
31 giving good conditions to discriminate the dif-
32 ferent underlying mechanisms. Then, prelim-
33 inary results have suggested that, similarly
34 to Cu and Co, a fraction of a monolayer of
35 strongly bound oxidized zinc species is formed
36 on a purposely hydroxylated Al₂O₃(0001) sur-
37 face.^{8,20,21} Finally, the domain of such strong Zn
38 adsorption is expected to cover a wider range
39 of oxygen/hydrogen conditions than for other
40 metals.²¹

41 The present work combines experimental
42 techniques, namely Surface Differential Reflec-
43 tivity Spectroscopy (SDRS) to determine the
44 growth mode and the adhesion energies, Tem-
45 perature Programmed Desorption (TPD) to
46 determine adsorption energies, X-ray Photoe-
47 mission Spectroscopy (XPS) to analyze chem-
48 ical states and *ab initio* atomistic simulations.
49 Thanks to a comparison between Zn adsorp-

tion/adhesion on a dry and on an hydroxy-
lated alumina surface, our results highlight the
conditions required to transform an interfacial
cleavage into a cohesive one. They reveal that
dispersed interfacial zinc oxide moieties formed
by the substitution of the hydroxyl protons by
Zn strongly bind to both the alumina substrate
and the zinc adlayers that are further deposited
upon the growth of the film. This conclusion is
substantiated by chemical characterization of
interfacial species, measurements and calcula-
tions of both adsorption and adhesion energies,
observation of hydrogen desorption and analy-
sis of interfacial charge transfers. It sketches a
general mechanism by which surface hydroxy-
lation opens a promising route towards a sys-
tematic improvement of wetting.

2 Methods

Experiments have been carried out in a vacuum
set-up (base pressure of $5 \cdot 10^{-9}$ Pa) involving a
load-lock system, a preparation chamber and a
main chamber.²² In the latter, samples were an-
alyzed by XPS with a Mg K α excitation source
and Low Energy Electron Diffraction (LEED).
The preparation chamber was equipped with
dedicated manipulators on which samples could
be cooled down to 100 K by circulating liquid
nitrogen and annealed up to 1500 K. An elec-
tron bombardment furnace was used to clean
the α -Al₂O₃(0001) substrates by repeated an-
nealing at 1200 K under an oxygen partial pres-
sure of $5 \cdot 10^{-4}$ Pa until they show carbon-free
XPS spectra and sharp (1×1) LEED patterns
(SI Section S2.5, Figure S7).

Hydroxylated (1×1) alumina surface were pre-
pared on purpose via adsorption-desorption of
thick ice layers formed by exposure to water
vapor at 100 K.^{5,10} The maximum obtained
OH coverage is $9 \cdot 10^{14}$ OH.cm⁻²,^{5,10,23} as es-
timated from the O 1s core level analysis,
i.e. about 2/3 of ML or one dissociated wa-
ter molecule per unit cell, in close agreement
with results of direct exposure to 1 mbar of wa-
ter vapor.^{10,11} Reconstructed α -Al₂O₃(0001)-
($\sqrt{31} \times \sqrt{31}$)R $\pm 9^\circ$ ²⁴ surfaces were prepared

by high temperature annealing above 1500 K in vacuum to serve as an OH-free alumina surface. Metallic zinc was deposited at a pressure in the high 1.10^{-8} Pa on surfaces held at 100 K to obtain a sizeable condensation coefficient.^{20,25} Deposition rates ranged between 0.17-0.34 ML/min as calibrated by a quartz microbalance. A continuous thin film model was also used to estimate film thickness through ratio of zinc and alumina photoemission peak area after correction of ionization cross section and spectrometer transmission function using tabulated mean free paths in bulk alumina and zinc (see SI Section S2.4). The growth of Zn films was analyzed *in situ* by SDRS which allows to estimate wetting angle (and adhesion energy) by fitting SDRS spectra with suitable dielectric models^{22,26-31} (SI, Section S2.1). Once the deposition was completed, the desorption energy of the film E_{des} was determined by TPD thanks to a differentially pumped mass spectrometer. Zn desorption has been analyzed in the framework of the so-called leading edge analysis³² which is applied to the onset of the thermal desorption spectra where changes in temperature and coverage are small enough to assume constant desorption parameters (SI, Section S2.2 and Figure S3).

In the absence of sizeable zinc core level shifts upon oxidation,^{33,34} the chemical state of Zn, was determined through the Zn $L_3M_{45}M_{45}$ Auger line probed in XPS. Fingerprint spectra corresponding to metallic zinc and zinc oxide are presented in supporting information (Section S2.3, Figures S5-S6).

Calculations were performed within the Density Functional Theory (DFT), implemented in VASP (Vienna *ab initio* simulation package).^{35,36} The interaction of valence electrons with ionic cores was described within the projector augmented wave (PAW) method,^{37,38} and the Kohn-Sham orbitals were developed on a plane-wave basis set with a cutoff energy of 400 eV. The dispersion-corrected GGA (optB88-vdW)³⁹⁻⁴¹ exchange-correlation functional was systematically used to improve the description of adhesion characteristics at weakly interacting metal/alumina interfaces,

such as between Zn and the non-polar Al-terminated (0001) surface.⁸ The above settings assure a satisfactory agreement between calculated and experimental characteristics of bulk Al_2O_3 , ZnO and Zn.⁴²

We have systematically considered the most stable stoichiometric Al-terminated alumina surface. The alumina substrate was represented by a slab composed of three -Al/3O/Al- layers, with equivalent adsorbates/interfaces at both terminations. The fully hydrated alumina surface involves one water molecule per surface unit cell. As mentioned above, this corresponds exactly to the maximum coverage which is experimentally observed. Adsorption in the limit of isolated Zn adatoms was approximated by a single Zn adsorbate per (1×1) alumina surface unit cell (1/3 ML). This corresponds to Zn-Zn distances of about 4.7 Å, considerably larger than the interatomic distances in bulk Zn. The adsorption energy was evaluated directly from total energy differences: $E_{ads} = -(E_{slab+Zn} - E_{slab} - E_{Zn})/2$. Free atom reference E_{Zn} was used, such that the adsorption energy directly provides information on the bonding strength between the metal adatom and the oxide surface. The energy barrier between two adsorption configurations was evaluated with 5-point climbing image nudged elastic band method.⁴³

The $Al_2O_3(0001) - (1 \times 1) \parallel Zn(0001) - (\sqrt{3} \times \sqrt{3})R30^\circ$ coincidence cell used in all interface calculations provides a particularly small mismatch between the two lattices ($\leq 3\%$) and produces numerically tractable supercells. Slabs of seven Zn(0001) layers were used to represent the zinc deposit. The adhesion strength at an A/B interface was estimated from the separation energy defined as $E_{sep} = -(E_{A/B} - E_A - E_B)/2S$, where $E_{A/B}$, E_A , and E_B are the total energies of the A/B heterostructure and separated A and B systems, respectively. Factor 2 accounts for the two equivalent A/B interfaces in each periodic unit cell and S is the interface area.

The in-plane lattice parameters of the heterostructures were fixed to those calculated for bulk alumina and the positions of all atoms were optimized until all components

of the residual forces were smaller than 0.01 eV/Å. In all calculations, a Γ -centered $8 \times 8 \times 1$ Monkhorst Pack grid for k-point sampling of the Brillouin zone was employed. Ionic charges were estimated within the partition scheme proposed by Bader^{44,45} and atomic configurations were plotted with VESTA.⁴⁶

3 Experimental results

Zn films were grown by vapor deposition at 100 K on either hydroxylated α -Al₂O₃(0001)-(1 × 1) surface or on reconstructed α -Al₂O₃(0001)-($\sqrt{31} \times \sqrt{31}$)R ± 9°²⁴ which are referred to as OH-covered and OH-free surfaces in the following (see Section 2). The latter was used as a reference of non-hydroxylated surface since the existence of an hydroxyl-free (1 × 1) surface is questionable.^{5,47} On OH-covered surfaces, a maximum of about 2/3 of monolayer (ML) or one dissociated water molecule per unit cell could be reached, consistently with the predicted stability of the non-polar alumina termination around room temperature and at low water vapor pressure.⁴⁸ The monolayer (ML) as used hereafter is defined as 1.52 10¹⁵ atoms.cm⁻² corresponding to three oxygen atoms per unit cell in the α -Al₂O₃(0001) structure. Experimental conditions have been described in Section 2 and the techniques are detailed in Supporting Information (SI, Section 2).

SDRS spectra recorded *in situ* during the growth of Zn films on OH-free and hydroxylated alumina surfaces are dominated by a band around 3.2 eV (SI, Figure S1) which lies within the high-energy tail of the Zn interband transitions.²² The comparison with the simulated response of a continuous two-dimensional film evidences a Volmer-Weber growth mode (SI, Figure S2). Dielectric modelling of the optical response with clusters represented by truncated spheres^{22,26-31} gives an average contact angle θ_c of 65° from which the adhesion energy can be estimated by means of the Young-Dupré formula $E_{adh} = \gamma_{Zn}(1 + \cos \theta_c)$ with zinc surface energy of $\gamma_{Zn} = 0.54$ J.m⁻² as determined

theoretically herein. This latter amounts to $E_{adh} = 0.75 \pm 0.1$ J.m⁻².

Thermal desorptions of Zn and H₂ from Zn/OH-free (Figure 1a) and Zn/OH-covered (Figure 1b) alumina were followed. The Polyani-Wigner analysis of the Zn peak line-shape (SI, Figure S3) and its shift with coverage (Figure 1c) evidence a fractional order of desorption as expected for supported clusters.⁴⁹ Reproducible measurements and the comparison of both surfaces showed that hydrogen desorbing from Zn/OH-free surfaces (Figure 1a) is not intrinsic to the sample. Indeed, the unavoidable H₂ desorption peak which systematically parallels that of Zn and the broad H₂ feature seen around 850 K are assigned to a reaction of the desorbed metallic Zn on the mass spectrometer walls and to the annealing of the sample holder, respectively. From a photoemission point of view (SI Section S2.3), the L₃M₄₅M₄₅ Auger lineshape demonstrates that Zn deposited on OH-free surfaces remains metallic upon annealing, even at 505 K (Figure 2a), well beyond the desorption maximum (Figure 1a), at a point where the Zn coverage is estimated to 0.06 ML. The expected spectroscopic fingerprint of oxidized Zn on the lower kinetic energy side of Zn L₃M₄₅M₄₅ Auger line seen on hydroxylated surface at 505 K (Figure 2b) is negligible on OH-free substrate (Figure 2a), which supports the above assumption that the H₂ desorption seen in Figure 1a does not come from the alumina surface. The desorption energy of Zn from OH-free alumina amounts to $E_{des} = 0.9 \pm 0.1$ eV/atom.

Compared to Figure 1a, two main extra characteristics are observed on H₂ desorption spectra from Zn/OH-covered alumina (Figure 1b). Firstly, H₂ and Zn desorption onsets do not coincide anymore and secondly, the dominant H₂ desorption occurs at temperatures higher than that at which the zinc ends desorbing, which suggests a complex Zn-OH reaction. In line with this, the kink observed at the onset of the Zn TPD spectra between 400 and 440 K (shown by an arrow in Figure 1c) corresponds to a shift of the desorption line towards higher temperature, *i.e.* to an increase in E_{des} . As seen from an accurate leading

Table 1: Estimates of desorption energies E_{des} and temperatures T_{des} of Zn/ α -Al₂O₃(0001) determined via thermal desorption (TPD) measurements by either leading edge (*) or Redhead’s (*) analysis. Experimental values are averaged over all measurements. Error bars correspond to standard deviations over several experiments.**

	Zn/OH-free alumina	Zn/OH-covered alumina	
	metallic Zn	metallic Zn/ oxidized Zn	oxidized Zn
E_{des} (eV/atom)	$0.9 \pm 0.1^*$	$1.15 \pm 0.05^*$	3.9^{**}
T_{des} (K)	> 400	> 430	~ 1380

edge desorption analysis (SI Section S2.2 and Figure S3), the value of Zn desorption energy (Table 1) measured on the OH-covered surface ($E_{des} = 1.15 \pm 0.05$ eV/atom) is higher than that recorded on the OH-free alumina ($E_{des} = 0.9 \pm 0.05$ eV/atom). The reproducible difference of desorption energies attested by the small values of the standard deviation (SI, Figure S4) provides an additional evidence for the occurrence of a chemical change within the Zn/OH-alumina film during the desorption process. The assumption is further substantiated by the direct observation of the oxidation state of Zn. Whatever the surface, Zn deposited at 100 K is always metallic, as shown by the perfect similarity of the Auger line (Figure 2) with reference spectra (SI, Figure S6), even down to coverages of the order of 1% of ML. In contrast with the total absence of oxidized zinc after deposition of zinc at 100 K on hydroxylated surfaces, the Zn L₃M₄₅M₄₅ lineshape undergoes a dramatic evolution upon annealing (Figure 2b). An oxide component appears in the Zn Auger line at 425 K, a temperature close to that at which the kink appears in the Zn desorption spectra (Figure 1c), until the broad profile associated to Zn²⁺ in pure ZnO^{50,51} (see SI, Figures S5-S6) is obtained at 505 K. The ionization of Zn mainly occurs at the onset of the desorption of Zn which is peaking between 480 and 525 K. Above 505 K, the Zn Auger lineshape and intensity are stable (Figure 2b). The oxidized zinc desorbs beyond 1380 K under vacuum, which corresponds to strongly bonded species having a desorption energy of $E_{des} \simeq 3.9$ eV, as given by the Redhead’s formula⁵² with a pre-exponential factor of $1 \cdot 10^{13}$ (Table 1, SI Section S2.2).

The persistence of metallic Zn upon anneal-

ing the Zn/OH-free alumina discards any role of either residual gases or impurities in the formation of oxidized Zn on the hydroxylated alumina. This proves instead that Zn reacts with the surface OH. The maximum amount of oxidized Zn that has been estimated from photoemission was $5 \cdot 10^{14}$ atoms.cm⁻², which corresponds to about one Zn per Al₂O₃ surface unit cell or to a Zn²⁺:OH ratio close to 1:2. Therefore, the Zn oxidation reaction involves nearly all the surface OH and is limited by the OH coverage.

Increase in desorption energy of Zn on hydroxylated alumina (Table 1) likely corresponds to an enhancement in the Zn/alumina adhesion energy. However, as a property of individual atoms, desorption energy may not show the same trend as adhesion which describes a collective behavior. To further explore this issue and the mechanism through which adsorption and adhesion enhancements occur, the interfaces of isolated Zn atoms and Zn films with dry and hydroxylated alumina surfaces were considered via Density Functional Theory (DFT) approaches (see Section 2).

4 Theoretical results

Guided by the experimental evidence, numerical simulations were successively performed for individual Zn atoms and for constituted Zn deposits on dry and hydroxylated non-polar alumina surfaces. Figure 3a shows the considered adsorption configurations of Zn adatoms under various environment conditions: adsorption on the dry surface (configuration A₁), on the fully hydroxylated surface (configuration A₂), and

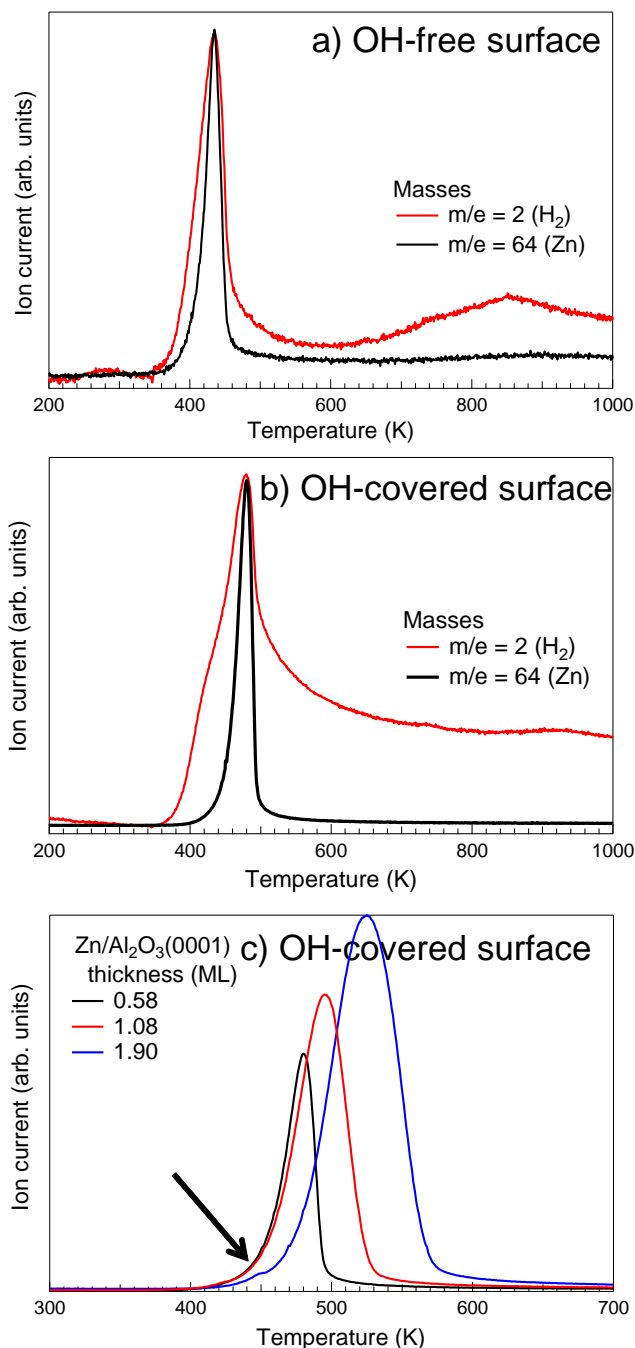


Figure 1: H_2 and Zn thermal desorption spectra from a) Zn/OH-free (0.9 ML thick Zn film) and b) Zn/OH-covered (0.4 ML thick Zn film) alumina surfaces. c) Zinc TPD spectra from Zn/OH-covered alumina for three different coverage; note the reproducible kink shown by an arrow for the highest coverage (see text). The heating rate is $0.5 \text{ K}\cdot\text{s}^{-1}$.

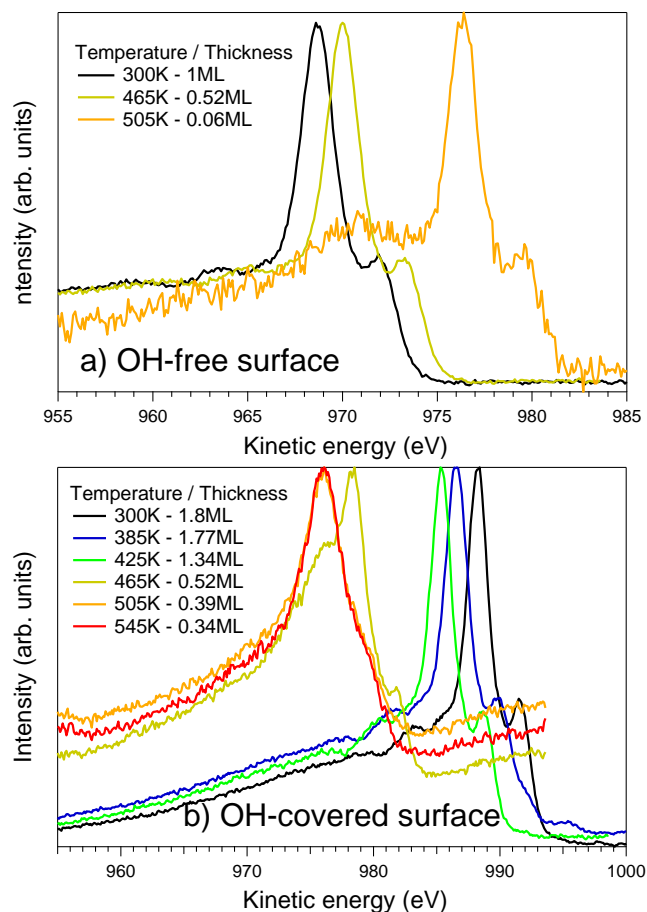


Figure 2: Zn $L_{3M_{45}M_{45}}$ Auger spectra: a) 1.0 ML thick Zn film on OH-free alumina surface annealed at increasing temperature (shown in figure): zinc remains metallic even at 505 K (see text); b) 1.8 ML thick Zn film on OH-covered alumina surface; note the change of lineshape from metallic Zn (300 to 425 K) to oxidized Zn (505 and 545 K) via a metal/oxide mixture (465 K). Spectra have been normalized to the maximum of intensity and not corrected from charge effects due to the insulating character of the alumina substrate.

on hydroxylated surface in H-lean conditions in which one (configuration A_3) or two (configuration A_4) hydrogen atoms per surface unit cell are absent. Table 2 gives the corresponding adsorption energies E_{ads} per Zn atom.

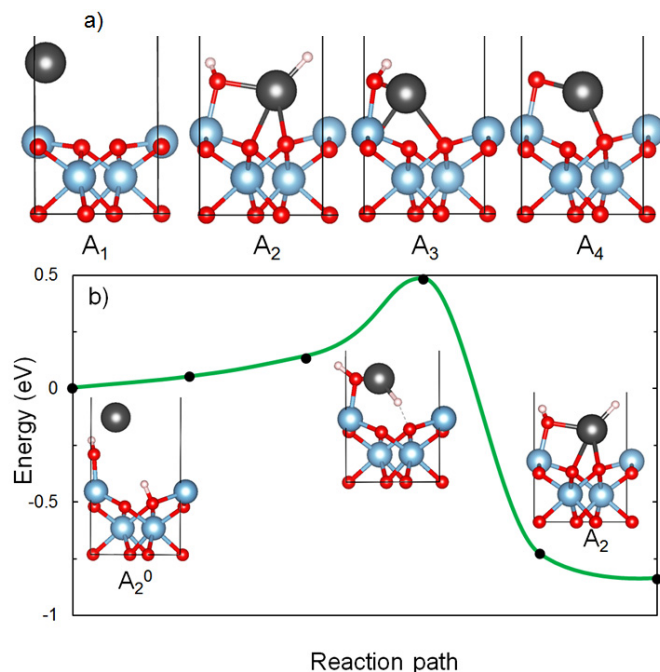


Figure 3: a) Adsorption configurations of Zn adatoms on a dry (A_1) and an hydroxylated (A_2 - A_4) Al_2O_3 (0001)- (1×1) surface under various environment conditions. b) Energy barrier between weakly (A_2^0) and strongly (A_2) adsorbed Zn configurations on the hydroxylated alumina surface (see text). Red, blue and grey balls stand for oxygen, aluminum and hydrogen atoms respectively.

Adsorption energies are found to increase along the series. On the dry surface (configuration A_1), E_{ads} is very weak, consistently with the post-transition character of Zn and its formally zero oxidation state. It is associated to a very weak electron transfer towards the alumina surface and a large adsorbate-surface distance ($> 3 \text{ \AA}$). E_{ads} is substantially enhanced on the hydroxylated surface (configuration A_2), upon an exchange of Zn with the hydrogen directly bound to a surface oxygen. This process, which can be schematized as $\text{OH}^- + \text{Zn} \rightarrow \text{O}^{2-} + (\text{ZnH})^+$, results in an ionization of the adsorbed Zn to the formal 2+ oxidation state (Bader charge $Q_{\text{Zn}} = 0.86 e$) and in a

Table 2: Adsorption and adhesion energies of Zn on the Al_2O_3 (0001) surface, associated to the configurations A, B, C represented in Figures 3 and 4. Corresponding Bader charges of the interfacial Zn atom Q_{Zn}^{at} and of the zinc deposit Q_{Zn}^{de} are also given. For reference $Q_{\text{Zn}} = 1.17 e$ in bulk ZnO.

Zn adsorption	A_1	A_2	A_3	A_4
E_{ads} (eV/Zn)	0.31	1.07	2.07	5.14
Q_{Zn}^{at} (e)	0.16	0.86	0.70	1.01
Zn adhesion	B_1	B_2	B_3	B_4
$E_{adh}(i_2)$ ($\text{J}\cdot\text{m}^{-2}$)	1.07	0.29	1.03	1.63
$E_{adh}(i_1)$ ($\text{J}\cdot\text{m}^{-2}$)	0.76	1.97	1.43	1.71
Q_{Zn}^{at} (e)	0.37	0.96	0.63	0.72
Q_{Zn}^{de} (e)	-0.33	0.04	0.12	0.53
Zn adhesion	C_1	C_2	C_3	C_4
$E_{adh}(i_2)$ ($\text{J}\cdot\text{m}^{-2}$)	1.08	0.23	1.59	2.54
$E_{adh}(i_1)$ ($\text{J}\cdot\text{m}^{-2}$)	0.65	1.15	1.11	1.80
Q_{Zn}^{me} (e)	0.09	0.05	0.49	1.26

negative charging of the hydrogen atom (Bader charge $Q_{\text{H}} = -0.34 e$, to be compared to its average Bader charge in surface hydroxyl groups $Q_{\text{H}} = 0.7 e$). The Zn adatom forms two bonds ($d_{\text{O-Zn}} < 2.5 \text{ \AA}$) with the surface oxygens and one with the oxygen from the OH^- group. We stress that, due to the passivating character of the surface hydroxyls, the zinc ionization is not spontaneous, but requires overcoming an energy barrier of about 0.5 eV (Figure 3b) with respect to an initial, weakly bound configuration A_2^0 ($E_{ads} = 0.23 \text{ eV}$). Finally, in the hydrogen-deficient configurations (configurations A_3 and A_4), the adsorption energies go on increasing as more H atoms are removed. This is principally due to the cost of the charge excess accommodation by the alumina surface upon desorption of neutral zinc atoms.

Figure 4 shows two alternative series of configurations (B_1 - B_4 and C_1 - C_4) for constituted Zn/ Al_2O_3 (0001) interfaces under conditions analogous to those of configurations A_1 to A_4 . In the series B the initially adsorbed Zn adatom is explicitly included, whereas it is absent in the series C. The corresponding adhesion

energies at the alumina termination [interface (i_1)] and at the Zn interface [interface (i_2)] are given in Table 2. Despite their different interface structures, the two series of configurations give fully consistent results.

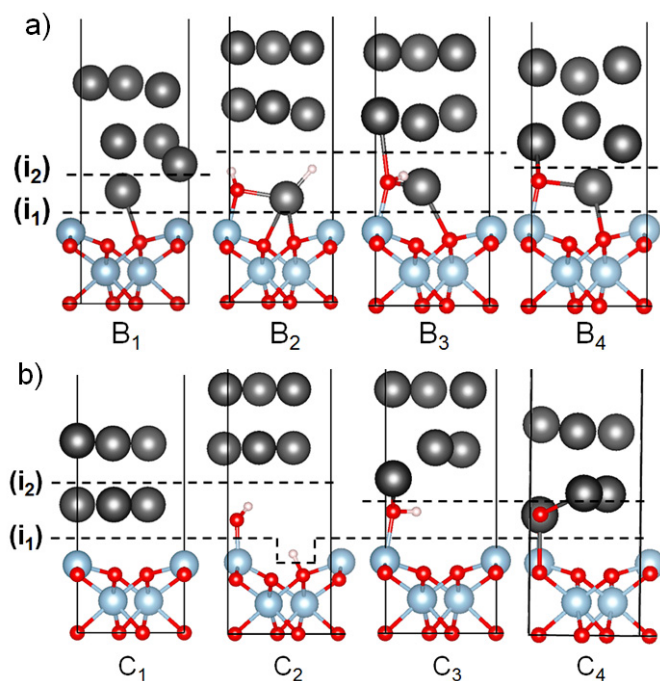


Figure 4: Two alternative series of configurations of a Zn deposit on a dry (B_1 or C_1) and a hydroxylated (B_2 - B_4 or C_2 - C_4) Al_2O_3 (0001)-(1×1) surface under various environment conditions (see text).

Both on the dry and on the fully hydroxylated surface (configurations B_1/C_1 and B_2/C_2), a weak interface is formed, either at (i_1) when the surface is dry, or at (i_2) when it is hydroxylated. These adhesion energies are weaker than the cleavage energy calculated for bulk Zn (1.08 J.m^{-2}), representative for the strength of the zinc film itself. We note that $E_{adh}(i_1)$ on the dry surface (configurations B_1/C_1) is only slightly stronger compared to the case of isolated adatoms (configuration A_1). On the hydroxylated surface (configurations B_2/C_2), a substantial adhesion is obtained at (i_1) interface but the interaction with the Zn overlayer (i_2) is in both cases too weak to provide a sufficiently good adhesion.

In contrast, under hydrogen-lean conditions (configurations B_3/C_3 and B_4/C_4), much better global adhesion performances are obtained,

simultaneously at (i_1) and (i_2) interfaces. The most striking effect is obtained in the absence of hydrogen (configuration B_4), where the interfacial ZnO species not only form strong Al-O and Zn-O bonds with the alumina surface, but also Zn-O bonds with the top Zn layers, characterized by a sizeable charge transfer and a reinforcement of Zn-Zn interaction in the interface vicinity. Interestingly, a very similar adhesion improvement under H-lean conditions is obtained with an alternative interfacial configuration (C_4), in which the number of interfacial bonds and charge distribution at the interface are similar to those in the configuration B_4 . This points to the generality of the calculated trends in interfacial energetics beyond a particular interface model. The ensemble of computational results highlights the key role of a dense network of *under-coordinated* interfacial anions remnants of surface hydroxyls in the formation of strong O-Al and O-Zn bonds at the interface, which enables the transformation of an interfacial cleavage into a cohesive one.

5 Discussion

The reported experimental and theoretical results, which describe the characteristics of the Zn-alumina interaction on the same hydroxylated $\alpha\text{-Al}_2\text{O}_3(0001)$ termination, consistently provide a thorough picture of the conditions under which surface hydroxylation is beneficial to adhesion.

As far as the regime of weak adsorption/adhesion of metallic Zn on the hydroxylated alumina surface in the absence of Zn-OH reaction is concerned, the calculated E_{ads} of 0.23 eV/atom for isolated zinc adatoms is fully consistent with the maximum temperature at which Zn adatoms can be experimentally stabilized on the alumina surface, *i.e.* around 220 K ²⁵ corresponding to $E_{ads} \approx 0.4 \text{ eV/atom}$.⁵² At higher Zn coverage, the computational estimate of E_{adh} in the absence of reaction (0.23 J.m^{-2} , configuration C_2) is smaller than that derived from SDRS measurements at 100 K (0.75 J.m^{-2}) (Table 1) maybe because of kinetic effects. However,

1 since all these estimates are lower than the Zn
2 cleavage energy (1.08 J.m^{-2}), both experiment
3 and theory demonstrate that in the absence
4 of Zn-OH reaction, the Zn/alumina cleavage
5 is interfacial, no matter whether the surface is
6 hydroxylated or not.

7 Under conditions such that zinc oxidation
8 takes place, both experimental and theoretical
9 results concur to evidence ionized Zn species
10 strongly bound to the alumina surface. In par-
11 ticular, Zn deposition on a pre-hydroxylated
12 surface, followed by hydrogen desorption, is
13 characterized by a calculated large adsorption
14 energy (configuration A₄, $E_{ads} = 5.14 \text{ eV/Zn}$
15 atom, Table 2), which is consistent with the es-
16 timate of the Zn²⁺ desorption energy ($E_{des} \simeq$
17 3.9 eV/Zn atom, estimated from the desorption
18 temperature of 1380 K, Tables 1). In addition,
19 in the presence of such strongly bound inter-
20 facial oxidized Zn species and after H desorp-
21 tion (configuration B₄), the calculated adhesion
22 energies [1.71 J.m^{-2} at (i₁) and 1.63 J.m^{-2} at
23 (i₂)] are both higher than the Zn cleavage en-
24 ergy (1.08 J.m^{-2}). These theoretical results are
25 confirmed by the experimentally measured in-
26 crease in the desorption energy of Zn⁰ in the
27 presence of Zn²⁺ ionized species.

28 Interestingly, both theory and experiment
29 agree that an activation is necessary to make
30 the transition between the two regimes —
31 absence of Zn-OH reaction or formation of
32 strongly bound Zn species. Theory proposes
33 (ZnH)⁺ moiety formation (configuration B₂) as
34 an intermediate step in this transition, followed
35 by hydrogen desorption that leaves the Zn ions
36 on the surface. This is supported by the TPD
37 observation of hydrogen desorption at temper-
38 atures higher than that at which metallic Zn
39 ends desorbing. Therefore, the oxidation of
40 zinc at the Zn/alumina interface is not enough
41 to switch from interfacial to cohesive cleavage,
42 but a full removal of hydrogen is also needed,
43 as proven by the link between the Zn chemical
44 state and the hydrogen desorption.

45 Finally, the cohesive nature of the Zn/alumina
46 cleavage that results from deposition and reac-
47 tion on the hydroxylated surface after hydro-
48 gen removal can be assigned to the formation
49 of strong O-Zn bonds, between the ionized Zn

atoms and the alumina surface [interface (i₁)]
and between interfacial oxygen atoms, reman-
nant of the hydroxyl group, and the Zn deposit
[interface (i₂)]. The latter are of mixed ionic-
covalent character, as revealed by a sizeable
charge transfer and, as such, give rise to an ad-
hesion energy much larger than the Zn cleavage
energy (1.63 J.m^{-2} versus 1.08 J.m^{-2} , Table 2).
It is to be stressed that no such enhancement of
adhesion at (i₂) exists if a full ZnO monolayer
is formed at the Zn/alumina interface accord-
ingly to simulations⁴² [$E_{adh} \sim 1.4\text{-}1.5 \text{ J.m}^{-2}$
at (i₁), but only $0.8\text{-}1.0 \text{ J.m}^{-2}$ at (i₂)]. The
weak adhesion at (i₂) in this case is due to a
higher coordination of interfacial oxygen ions,
which makes their bonding with the Zn deposit
weaker. This comparison highlights the key role
of the under-coordination of interfacial oxygen
species, such as those involved in dispersed
ZnO moieties formed on the pre-hydroxylated
surface. It shows that an initial surface hydrox-
ylation may conveniently provide the quantity
of residual anions which is both necessary and
sufficient for the stabilization of a constituted
zinc deposit on the alumina surface.

6 Conclusion

In summary, by combining experimental and
theoretical evidences, we have shown that sur-
face pre-hydroxylation may lead to a dramatic
enhancement of zinc adsorption/adhesion. We
demonstrate that, while zinc adsorbs very
weakly either on OH-free alumina or on hy-
droxylated alumina in the absence of Zn-OH
reaction, an activated adsorption on the OH-
covered surface followed by hydrogen desorp-
tion produces interfacial oxidized Zn species
and under-coordinated oxygen ions. Most in-
terestingly, the measured and calculated in-
creases of metallic zinc binding in the pres-
ence of such oxidized species point unambigu-
ously towards an overall interface strengthen-
ing. Computational results rationalize the pro-
cess and, beyond the expected strong interac-
tion of interfacial ionized Zn with the alumina
surface, they highlight the key role of under-

coordinated interfacial anions, remnants of the surface hydroxylation layer which are responsible for the switch from interfacial cleavage for Zn/OH-free alumina to cohesive cleavage for Zn/hydroxylated alumina. The novelty of the scenario proposed herein is to link the improvement in adhesion to the entire interfacial chemistry between the metallic adlayer and the surface hydroxyl groups. By pinpointing the role played by each species involved in the interface, metal, oxygen and hydrogen, it sets up a general framework to investigate whether hydroxyl groups are prone to enhance the adhesion at any given metal/oxide interface.

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Supporting Information Available

The following files are available free of charge. Description (S1) of the galvanization context of the study, (S2.1) of the differential reflectivity modeling, (S2.2) of the thermal desorption analysis, (S2.3) of the Zn LMM Auger line-shape, (S2.4) of zinc film thickness determination and (S2.5) of the LEED patterns.

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